Broadband 2-Stage LNA 1 - 6 GHz



MAAL-011188

Rev. V2

Features

- Broadband 2-Stage LNA
- Gain:

35.2 dB @ 2.50 GHz 35.1 dB @ 3.75 GHz 35.2 dB @ 4.70 GHz

Noise Figure:

0.79 dB @ 2.50 GHz 0.86 dB @ 3.75 GHz 0.92 dB @ 4.70 GHz

- Single 5 V Supply
- Enable Pin with 1.8 V logic
- Low DC Current: 80 mA
- Lead-Free 3 mm 16 Lead QFN Package
- RoHS* Compliant

Applications

- 5G Massive MIMO
- Wireless Infrastructure
- General purpose wireless
- TDD or FDD systems

Description

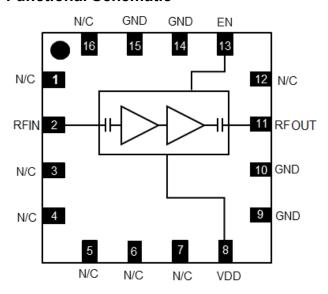
The MAAL-011188 is a compact surface mount, highly integrated 2-stage low noise amplifier (LNA). This LNA is designed for operation from 1 to 6 GHz and is housed in a lead-free 3 mm 16-lead QFN plastic package.

The MAAL-011188 features low noise figure, high gain and low power consumption. The LNA requires a single 5 V supply and the Enable pin is 1.8 V CMOS compatible. All the bias circuitry and matching components are internal to the device.

Ordering Information

Part Number	Package
MAAL-011188-TR1000	1000 part reel
MAAL-011188-001SMB	Sample Board

Functional Schematic



Pin Configuration¹

Pin#	Pin Name	Description
1,3,4,5,6, 7,12,16	N/C	No Connect
9,10, 14,15	GND	Ground
2	RFIN	RF Input
8	VDD	Supply Voltage
11	RFOUT	RF Output
13	EN	LNA Enable
17	Paddle ²	Ground

- MACOM recommends connecting GND and N/C pins to ground.
- The exposed pad centered on the package bottom must be connected to PCB ground with low electrical and thermal resistances.

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive



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AC Electrical Specifications (LNA ON Mode): P_{IN} = -30 dBm, T_C = +25°C, V_{DD} = 5 V, Z_0 = 50 Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	2.50 GHz 3.75 GHz 4.70 GHz	dB	32 32 —	35.2 35.1 35.2	_
Input IP3	P _{IN} /tone = -30 dBm, Tone Delta = 2 MHz, 2.50 GHz 3.75 GHz 4.70 GHz	dBm	_	-5.2 -3.7 -4.8	_
Input P1dB	2.50 GHz 3.75 GHz 4.70 GHz	dBm	_	-17.4 -17.6 -18.8	_
Noise Figure	2.50 GHz 3.75 GHz 4.70 GHz	dB	_	0.79 0.86 0.92	
RF _{IN} Port Return Loss	RF _{IN} Port, 2.50 GHz RF _{IN} Port, 3.75 GHz RF _{IN} Port, 4.70 GHz	dB	_	24 21 18	_
RF _{OUT} Port Return Loss	RF _{OUT} Port, 2.50 GHz RF _{OUT} Port, 3.75 GHz RF _{OUT} Port, 4.70 GHz	dB	_	15 20 16	_
Reverse Isolation	2.50 GHz 3.75 GHz 4.70 GHz	dB	_	55 56 55	_

Transient Electrical Specifications:

Freq. = 2.5 GHz, P_{IN} = -30 dBm, T_{C} = 25°C, V_{DD} = 5 V, Z_{0} = 50 Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
EN Gain Settling Time	RF _{IN} to RF _{OUT} gain settling time within 0.3 dB of final value after EN command	μs	_	0.3	_
Power on Gain Settling Time	RF _{IN} to RF _{OUT} gain settling time within 0.5 dB of final value after DC power on	ms	_	1	_

DC Electrical Specifications: $T_C = 25^{\circ}C$, $V_{DD} = 5$ V, $Z_0 = 50$ Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Supply Voltage		V	4.75	5	5.25
Amplifier Bias Current	LNA ON Mode Disable Mode	mA	_	80 2.3	_
EN Control Voltage	LNA ON Mode, Logic High Disable Mode, Logic Low	V	_	1.8 0	_
EN Logic Input Current	LNA ON Mode, Logic High Disable Mode, Logic Low	μA	_	40 +/-0.03	_

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Control Truth Table

EN Control				
LNA ON Mode	Logic High			
Disable Mode	Logic Low or Open			

Absolute Maximum Ratings^{3,4}

Parameter	Absolute Maximum
RF _{IN} Input Power ⁵ Freq. = 3.75 GHz: LNA ON Mode	23 dBm LTE (8 dB PAR), 26 dBm CW
DC Voltages: V _{DD} & RF _{IN} EN & RF _{OUT}	-0.5 to +5.5 V -0.5 to +2.75 V
Junction Temperature: LNA ON Mode ^{6,8}	+150°C
Operating Temperature ⁷	-40°C to +105°C
Storage Temperature	-55°C to +150°C

- 3. Exceeding any one or combination of these limits may cause permanent damage to this device.
- 4. MACOM does not recommend sustained operation near these survivability limits.
- 5. Single event, up to 10 seconds duration.
- Operating at nominal conditions with T_J ≤ +150°C (LNA ON Mode) will ensure MTTF >> 1 x 10⁶ hours.
- 7. Operating/Case temperature (T_C) is the temperature of the exposed paddle.
- 8. Junction Temperature (T_J) = T_C + Θ_{JC} * P_{DISS} where P_{DISS} is the total DC & RF dissipated power.
 - LNA ON Mode: Typical thermal resistance (Θ_{JC}) = 33.4°C/W.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 1 A and CDM Class C3 devices.

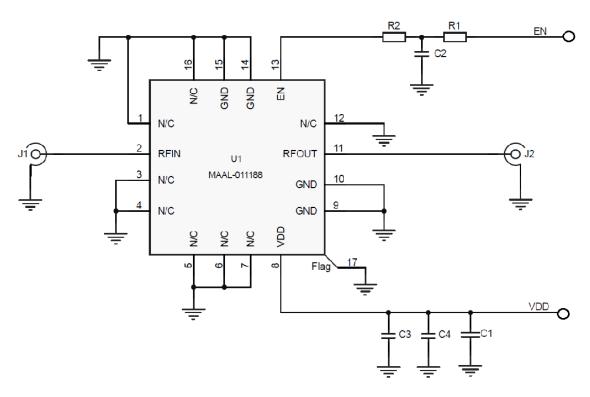
Power Supplies

De-coupling capacitors should be placed at the VDD supply pin to minimize noise and fast transients. Supply voltage change or transients should have a slew rate smaller than 1 V / 10 μ s. In addition, all control pins should remain at 0 V (+/- 0.3 V) and no RF power should be applied while the supply voltage ramps or while it returns to zero.

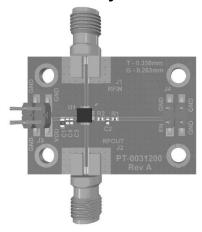


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Sample Board Schematic



Sample Board PCB Layout



Parts List

Part	Value	Case style
C1	10 μF	0603
C2	5 pF	0402
C3	470 pF	0402
C4	10 nF	0402
R1	1 kΩ	0402
R2	100 Ω	0402

• Material: Rogers 4003C

Dielectric thickness: 0.203 mm
Track/Carry 0.350/0.363 mm

Track/Gap: 0.350/0.263 mm

Finished copper thickness: 44 μm +/- 10 μm

Finish both sides: 0.075 μm gold over 4.5μm nickel

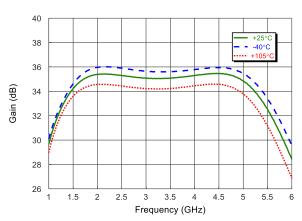
Further layout information available on request

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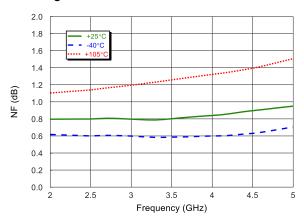
Typical Performance Curves:

 $P_{IN} = -30$ dBm, $V_{DD} = 5$ V, $T_C = +25$ °C, $Z_0 = 50$ Ω (unless otherwise indicated)

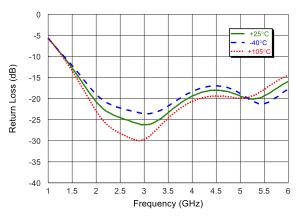
Gain⁹



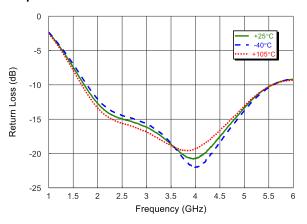
Noise Figure⁹



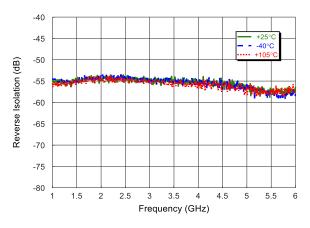
Input Return Loss



Output Return Loss



Port Reverse Isolation - RX Mode



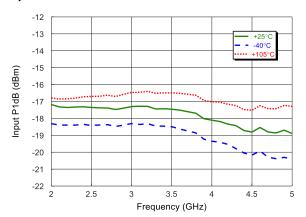
9. For gain, noise figure and isolation plots, RF trace and connector losses are de-embedded.



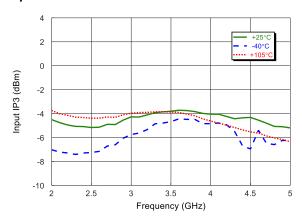
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Typical Performance Curves: P_{IN} = -30 dBm, V_{DD} = 5 V, T_{C} = +25°C, Z_{0} = 50 Ω (unless otherwise indicated)

Input P1dB



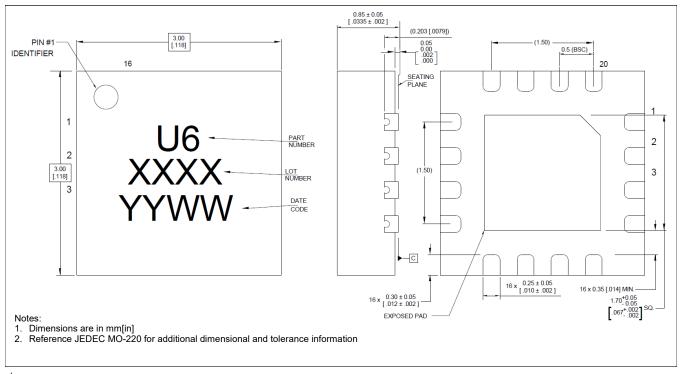
Input IP3





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Lead-Free 3 mm 16-Lead QFN[†]



[†] Reference Application Note S2083 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements in accordance to JEDEC J-STD-020D. Plating is NiPdAu over Copper

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